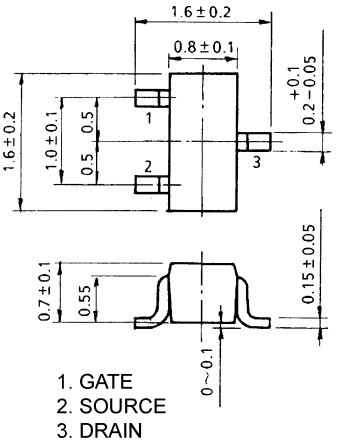
TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

# SSM3J36FS

## ○ Power Management Switches

- 1.5-V drive
- Low ON-resistance: $R_{on}$ = 3.60 Ω (max) (@$V_{GS}$ = -1.5 V)
  : $R_{on}$ = 2.70 Ω (max) (@$V_{GS}$ = -1.8 V)
  : $R_{on}$ = 1.60 Ω (max) (@$V_{GS}$ = -2.8 V)
  : $R_{on}$ = 1.31 Ω (max) (@$V_{GS}$ = -4.5 V)

Unit: mm




| | |
|---|---|
| SSM | |
| JEDEC | — |
| JEITA | — |
| TOSHIBA | 2-2H1B |

Weight: 2.4 mg (typ.)

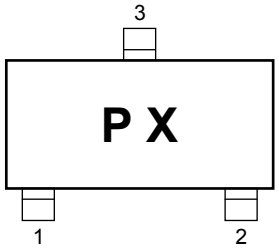
## Absolute Maximum Ratings (Ta = 25 °C)

| Characteristics | | Symbol | Rating | Unit |
|---|---|---|---|---|
| Drain-source voltage | | $V_{DSS}$ | -20 | V |
| Gate-source voltage | | $V_{GSS}$ | ±8 | V |
| Drain current | DC | $I_D$ | -330 | mA |
| | Pulse | $I_{DP}$ | -660 | |
| Drain power dissipation | | $P_D$ (Note1) | 150 | mW |
| Channel temperature | | $T_{ch}$ | 150 | °C |
| Storage temperature range | | $T_{stg}$ | −55 to 150 | °C |

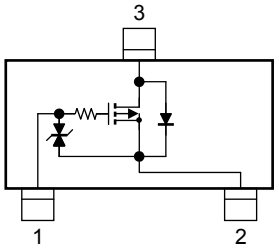
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/ “Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Mounted on an FR4 board
(25.4 mm × 25.4 mm × 1.6mm, Cu Pad: 0.36 $mm^2$ ×3)

## Marking




## Equivalent Circuit (top view)




## Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

## Usage Considerations

Let $V_{th}$ be the voltage applied between gate and source that causes the drain current ($I_D$) to below −1 mA for the SSM3J36FS). Then, for normal switching operation, $V_{GS(on)}$ must be higher than $V_{th}$, and $V_{GS(off)}$ must be lower than $V_{th}$. This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

Start of commercial production
2008-06

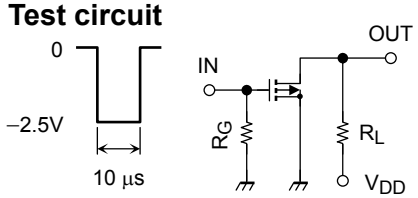
## Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Conditions | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|---|
| Drain-source breakdown voltage | | $V_{(BR)\ DSS}$ | $I_D$ = -1 mA, $V_{GS}$ = 0 V | -20 | — | — | V |
| | | $V_{(BR)\ DSX}$ | $I_D$ = -1 mA, $V_{GS}$ = 8 V | -12 | — | — | |
| Drain cutoff current | | $I_{DSS}$ | $V_{DS}$ = -16 V, $V_{GS}$ = 0 V | — | — | -10 | μA |
| Gate leakage current | | $I_{GSS}$ | $V_{GS}$ = ±8 V, $V_{DS}$ = 0 V | — | — | ±1 | μA |
| Gate threshold voltage | | $V_{th}$ | $V_{DS}$ = -3 V, $I_D$ = -1 mA | -0.3 | — | -1.0 | V |
| Forward transfer admittance | | $\|Y_{fs}\|$ | $V_{DS}$ = -3 V, $I_D$ = -100mA (Note2) | 190 | — | — | mS |
| Drain-source ON-resistance | | $R_{DS\ (ON)}$ | $I_D$ = -100mA, $V_{GS}$ = -4.5 V (Note2) | — | 0.95 | 1.31 | Ω |
| | | | $I_D$ = -80mA, $V_{GS}$ = -2.8 V (Note2) | — | 1.22 | 1.60 | |
| | | | $I_D$ = -40mA, $V_{GS}$ = -1.8 V (Note2) | — | 1.80 | 2.70 | |
| | | | $I_D$ = -30mA, $V_{GS}$ = -1.5 V (Note2) | — | 2.23 | 3.60 | |
| Input capacitance | | $C_{iss}$ | $V_{DS}$ = -10 V, $V_{GS}$ = 0 V, f = 1 MHz | — | 43 | — | pF |
| Output capacitance | | $C_{oss}$ | | — | 10.3 | — | |
| Reverse transfer capacitance | | $C_{rss}$ | | — | 6.1 | — | |
| Total Gate Charge | | $Q_g$ | $V_{DS}$ = -10 V, $I_{DS}$= -330mA, $V_{GS}$ = -4 V | — | 1.2 | — | nC |
| Gate−Source Charge | | $Q_{gs}$ | | — | 0.85 | — | |
| Gate−Drain Charge | | $Q_{gd}$ | | — | 0.35 | — | |
| Switching time | Turn-on time | $t_{on}$ | $V_{DD}$ = -10 V, $I_D$ = -100mA $V_{GS}$ = 0 to -2.5 V, $R_G$ = 50Ω | — | 90 | — | ns |
| | Turn-off time | $t_{off}$ | | — | 200 | — | |
| Drain-source forward voltage | | $V_{DSF}$ | $I_D$ =330mA, $V_{GS}$ = 0 V (Note2) | — | 0.88 | 1.2 | V |

Note2: Pulse test

## Switching Time Test Circuit

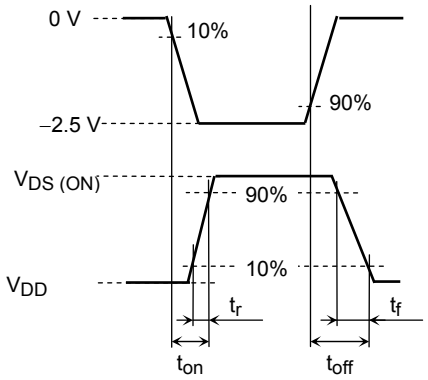
**(a) Test circuit**



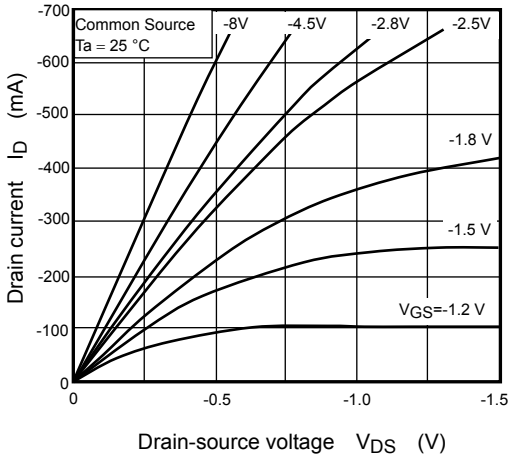

$V_{DD}$ = −10 V
Duty ≤ 1%
$V_{IN}$: $t_r$, $t_f$ < 5 ns
($Z_{out}$ = 50 Ω)
Common Source
Ta = 25°C

**(b) $V_{IN}$**

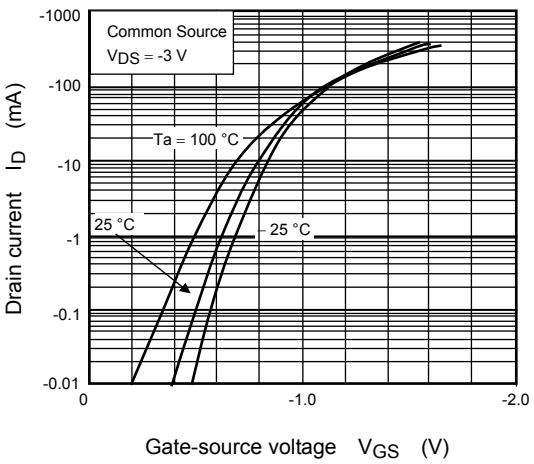
**(c) $V_{OUT}$**



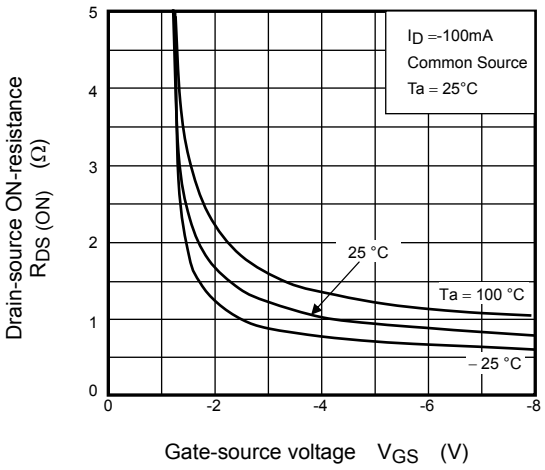
$I_D - V_{DS}$



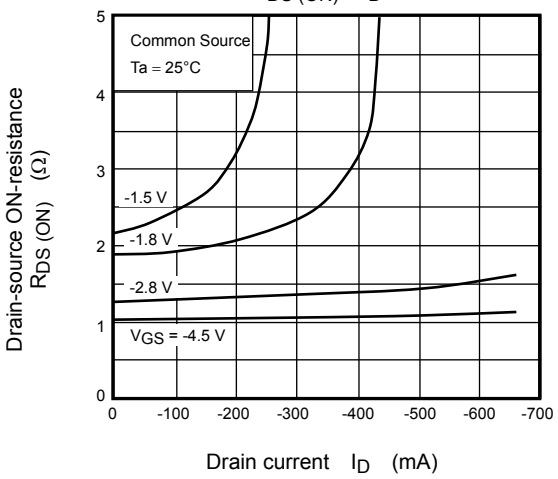

$I_D - V_{GS}$



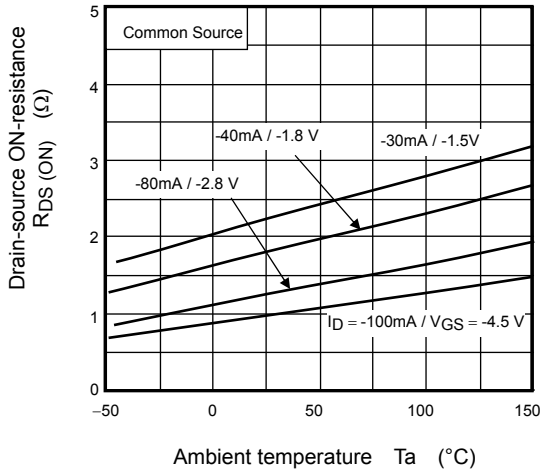

$R_{DS\ (ON)} - V_{GS}$



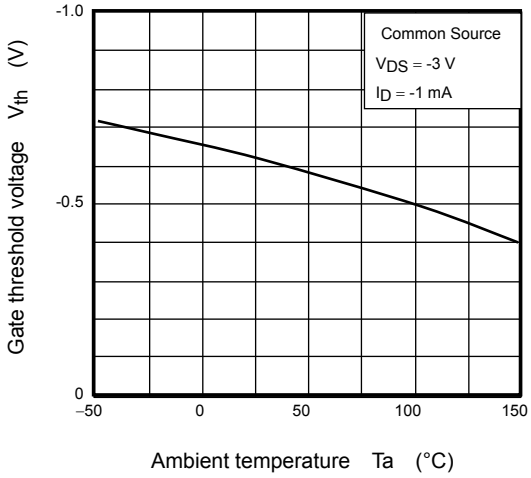

$R_{DS\ (ON)} - I_D$

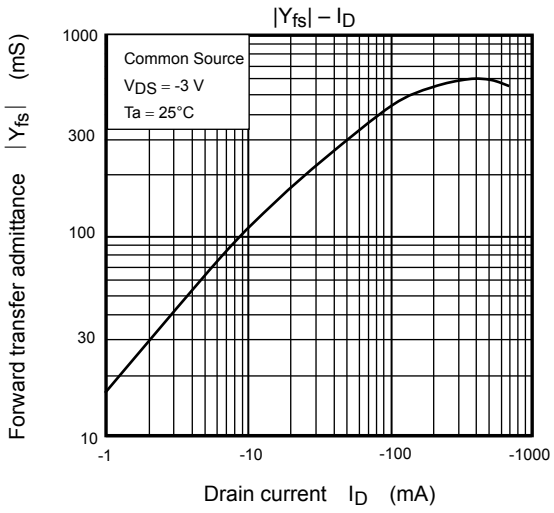


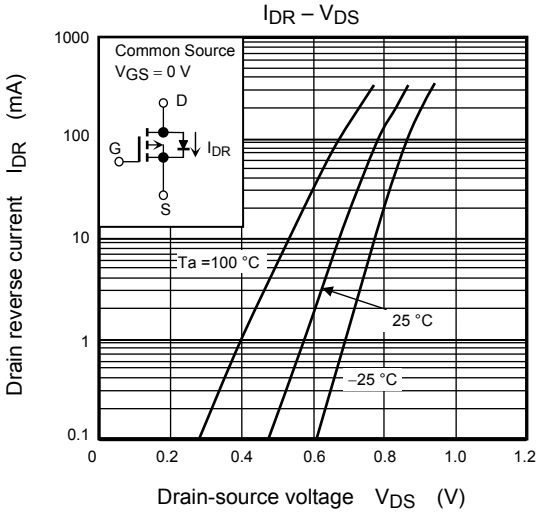

$R_{DS\ (ON)} - Ta$

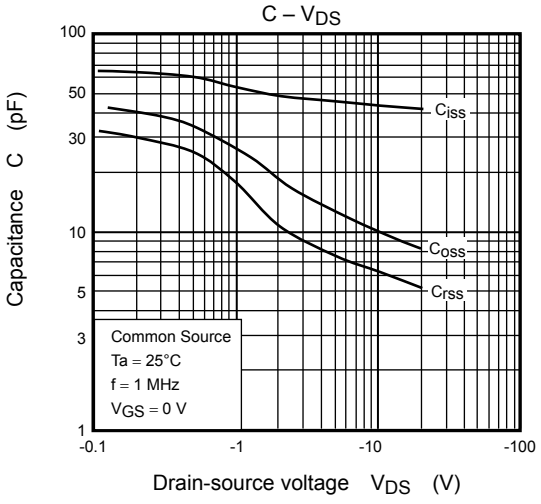


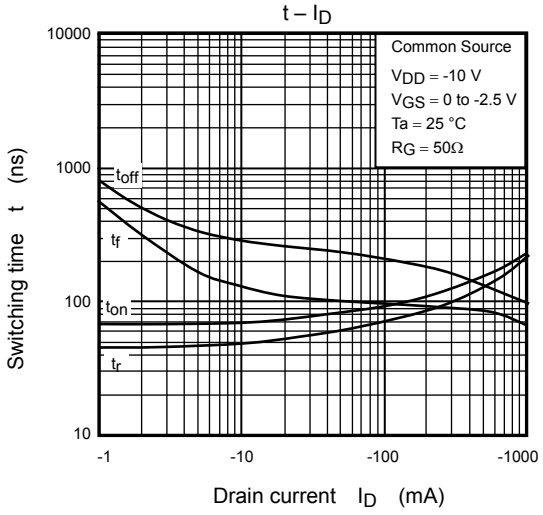

$V_{th} - Ta$

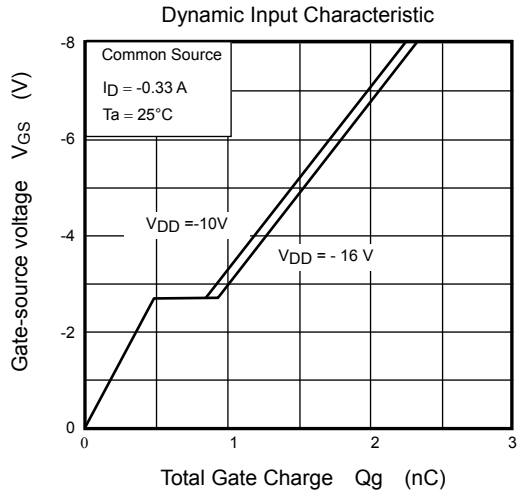


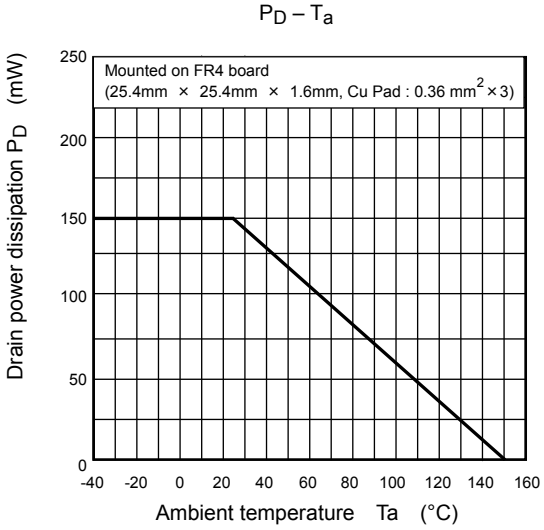

|Yfs| – ID
Common Source
VDS = -3 V
Ta = 25°C
Forward transfer admittance |Yfs| (mS)
Drain current ID (mA)
1000
300
100
30
10
-1
-10
-100
-1000


IDR – VDS
Common Source
VGS = 0 V
D
G
S
IDR
Ta =100 °C
25 °C
−25 °C
Drain reverse current IDR (mA)
Drain-source voltage VDS (V)
1000
100
10
1
0.1
0
0.2
0.4
0.6
0.8
1.0
1.2


C – VDS
Ciss
Coss
Crss
Common Source
Ta = 25°C
f = 1 MHz
VGS = 0 V
Capacitance C (pF)
Drain-source voltage VDS (V)
100
50
30
10
5
3
1
-0.1
-1
-10
-100


t – ID
Common Source
VDD = -10 V
VGS = 0 to -2.5 V
Ta = 25 °C
RG = 50Ω
toff
tf
ton
tr
Switching time t (ns)
Drain current ID (mA)
10000
1000
100
10
-1
-10
-100
-1000


Dynamic Input Characteristic
Common Source
ID = -0.33 A
Ta = 25°C
VDD =-10V
VDD = - 16 V
Gate-source voltage VGS (V)
Total Gate Charge Qg (nC)
-8
-6
-4
-2
0
0
1
2
3


PD – Ta
Mounted on FR4 board
(25.4mm × 25.4mm × 1.6mm, Cu Pad : 0.36 mm2 × 3)
Drain power dissipation PD (mW)
Ambient temperature Ta (°C)
250
200
150
100
50
0
-40
-20
0
20
40
60
80
100
120
140
160

## RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, Class 3 medical devices, equipment used for automobiles, and military vehicles and munitions. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

ENTEGRECİ

Bu belge www.entegreci.com üzerinden sunulmaktadır.

# Elektronik komponent tedarikinde Entegreci

Entegreci, Eskişehir merkezli, Türkiye geneline satış yapan bir elektronik komponent mağazasıdır. Entegreler (IC), mikrodenetleyiciler, transistörler, diyotlar, pasif elemanlar, konnektörler, modüller ve geliştirme kartları tek adetten seri üretim adetlerine kadar satılır. Ürün sayfalarında güncel stok durumunu, fiyatı ve datasheet bağlantısını bulabilirsiniz.

### Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

**www.entegreci.com**

### Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

**Kategorilere göz atın**

### Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

**Üreticileri görün**

### Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

**Teklif isteyin**

**www.entegreci.com** | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.